TOSHIBA TB6865AFG

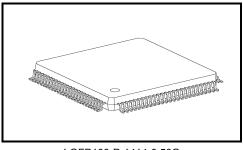
TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

TB6865AFG

Qi compliant wireless power transmitter IC

1. Outline

The TB6865AFG is wireless power transmitter (TX) IC for Qi low power v1.1 compliant of Wireless Power Consortium (WPC). TB6865AFG includes ARM Core Tex M3, PWM control, PreDriver ASK demodulate circuits for wiress power taransfer system. The IC includes all TX functions needed to construct a standalone wireless power system.



LQFP100-P-1414-0.50G

2. Applications

Mobile devices (Smartphone, tablet), Mobile accessory etc.

3. Features

• Cortex-M3 manufactured by ARM is used

RAM : 8KbyteFlash ROM : 128Kbyte

• Pre driver (Drive 4× Full Bridge circuit) / High Resolution PWM(100Hz step): 16 channels

12-bit Analog/Digital Converter(ADC)
 14 channels
 ASK signal input
 4 channels
 Input Output ports
 64 pins

Large current for LED drive: 6 pins / Control for buzzer: 1 pin

General-purpose serial interface(UART) : 2 channels
 Serial bus interface(I²C bus) : 1 channel

• 3.3V LDO

• Fail safe function (Over voltage detection, Over current detection, and Thermal shut down)

• Maximum operation frequency

CPU : 20MHz PWM : 80MHz

• Operating voltage range

Analog and pre driver $\div 4.5 \text{V to } 14 \text{V}$ Digital $\div 2.7 \text{V to } 3.6 \text{V}$

 $\bullet \ \ Package \\ \vdots \ LQFP100 - P-1414 - 0.50G \ (14mm \times 14mm, \ 0.5mm \ pitch)$

About solder ability, following conditions were confirmed

Solder ability

(1) Use of Sn-37Pb solder Bath

• solder bath temperature = 230°C

• dipping time = 5 seconds

the number of times = onceuse of R-type flux

(2) Use of Sn-3.0Ag-0.5Cu solder Bath

• solder bath temperature = 245°C

• dipping time = 5 seconds

• the number of times = once

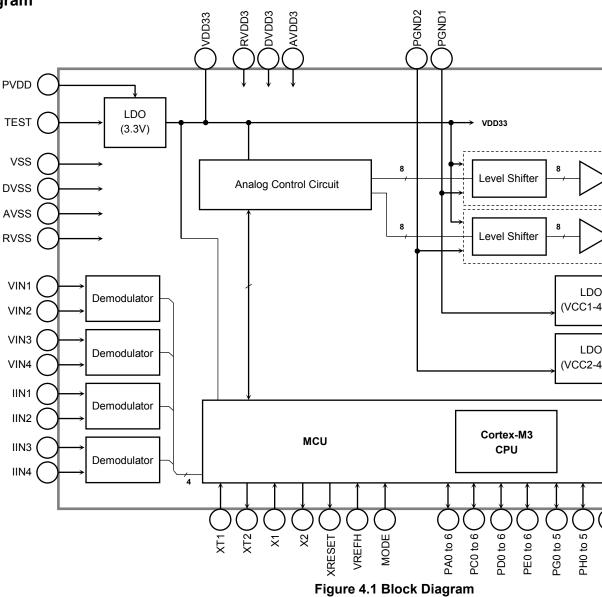
· use of R-type flux

This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge by using an earth strap, a conductive mat and an ionizer. Ensure also that the ambient temperature and relative humidity are maintained at reasonable levels.

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4. Block Diagram



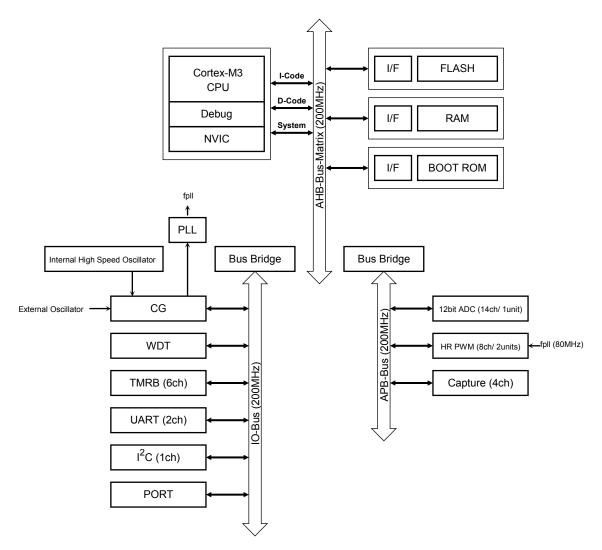


Figure 4.2 Block Diagram (CPU Core)

5. Pin Assignment

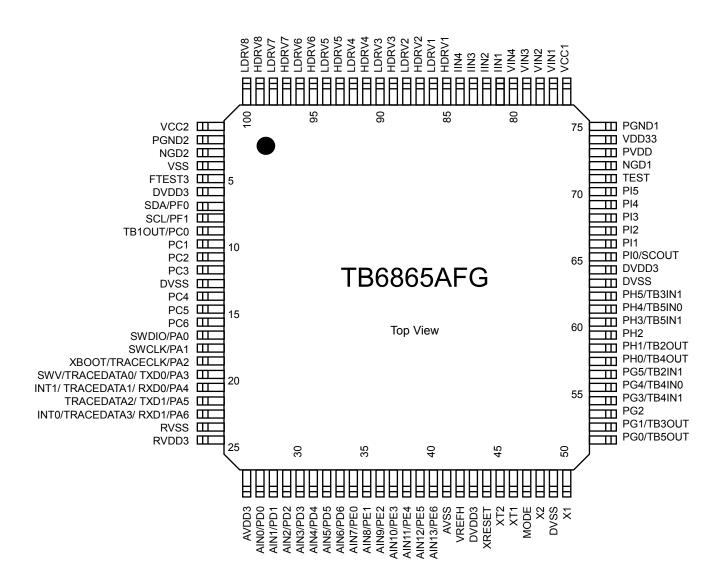


Figure 5.1 Pin Assignment

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6. Pin Function

Table 6.1 Pin Function

Pin Number	Pin symbol	I/O	Description	Comment
1	VCC2	-	Power supply pin for CH5 to CH8 pre-drivers 2	(Note 1)
2	PGND2	-	Power GND pin for Analog circuit	(Note 2)
3	NGD2	0	VCC2-4.5V LDO output pin for internal circuit 2	(Note 3)
4	VSS	-	Analog GND pin	(Note 2)
5	FTEST3	I	TEST pin	(Note 4)
6	DVDD3	-	Power supply pin for Digital circuit	
7	PF0	I/O	Input Output Port	
7	SDA	I/O	Serial data input output	I ² C bus(SDA)
0	PF1	I/O	Input Output Port	
8	SCL	I/O	Serial clock input output	I ² C bus(SCL)
0	PC0	I/O	Input Output Port	
9	TB1OUT	0	TMRB1 Output	Control for Buzzer
10	PC1	I/O	Input Output Port	Large current for LED drive
11	PC2	I/O	Input Output Port	Large current for LED drive
12	PC3	I/O	Input Output Port	Large current for LED drive
13	DVSS	-	GND pin	(Note 2)
14	PC4	I/O	Input Output Port	Large current for LED drive
15	PC5	I/O	Input Output Port	Large current for LED drive
16	PC6	I/O	Input Output Port	Large current for LED drive
47	PA0	I/O	Input Output Port	
17	SWDIO	I/O	Serial Wire debug port	Debug port
40	PA1	I/O	Input Output Port	
18	SWCLK	ı	Serial Wire clock	Debug port
	PA2	I/O	Input Output Port	
19	TRACECLK	0	TRACE clock output	Debug port
	XBOOT	ı	Single boot mode	
	PA3	I/O	Input Output Port	
00	TXD0	0	TXD0	
20	TRACEDATA0	0	TRACE data output 0	Debug port
	SWV	0	Serial Wire Viewer output	
	PA4	I/O	Input Output Port	
0.4	RXD0	I	RXD0	
21	TRACEDATA1	0	TRACE data output 1	Debug port
	INT1	I	External Interrupt 1	

Note 1: When it's not in use, connect to GND.

Note 2: Connect to common ground(GND).

Note 3: It is impossible to supply power to external parts. Connect capacitor $(0.01 \mu F)$ between NGD2 and VCC2.

Note 4: Must be open.

Table 6.2 Pin Function

Pin Number	Pin symbol	I/O	Description	Comment
	PA5	I/O	Input Output Port	
22	TXD1	0	TXD1	UART(TXD)
	TRACEDATA2	0	TRACE data output 2	Debug port
	PA6	I/O	Input Output Port	
23	RXD1	I	RXD1	UART(RXD)
23	TRACEDATA3	0	TRACE data output 3	Debug port
	INT0	I	External Interrupt 0	
24	RVSS	-	GND pin	(Note 2)
25	RVDD3	-	Power supply pin for Regulator	
26	AVDD3	-	Power supply pin for ADC	
07	PD0	I/O	Input Output Port	
27	AIN0	I	ADC input	
20	PD1	I/O	Input Output Port	
28	AIN1	I	ADC input	
20	PD2	I/O	Input Output Port	
29	AIN2	I	ADC input	
20	PD3	I/O	Input Output Port	
30	AIN3	I	ADC input	
24	PD4	I/O	Input Output Port	
31	31 AIN4	I	ADC input	
22	PD5	I/O	Input Output Port	
32	AIN5	I	ADC input	
22	PD6	I/O	Input Output Port	
33	AIN6	I	ADC input	
34	PE0	I/O	Input Output Port	
34	AIN7	I	ADC input	
35	PE1	I/O	Input Output Port	
33	AIN8	ı	ADC input	
36	PE2	I/O	Input Output Port	
30	AIN9	ı	ADC input	
37	PE3	I/O	Input Output Port	
57	AIN10	I	ADC input	
38	PE4	I/O	Input Output Port	
30	AIN11	I	ADC input	
39	PE5	I/O	Input Output Port	
J8	AIN12	I	ADC input	
40	PE6	I/O	Input Output Port	
40	AIN13	I	ADC input	
41	AVSS	-	GND pin	(Note 2)
42	VREFH	ı	Analog reference input pin for A/D conversion	
43	DVDD3	-	Power supply pin for Digital circuit	

Table 6.3 Pin Function

Pin Number	Pin symbol	I/O	Description	Comment
44	XRESET	I	External RESET input	
45	XT2	0	Low frequency oscillator output	(Note E)
46	XT1	I	Low frequency oscillator input	(Note 5)
47	MODE	I	TEST pin	(Note 6)
48	X2	0	High frequency oscillator output	(Note 7)
49	DVSS	-	GND pin	(Note 2)
50	X1	1	High frequency oscillator input	(Note 7)
E4	PG0	I/O	Input Output Port	
51	TB5OUT	0	TMRB5 Output	
50	PG1	I/O	Input Output Port	
52	TB3OUT	0	TMRB3 Output	
53	PG2	I/O	Input Output Port	
F.4	PG3	I/O	Input Output Port	
54	TB4IN1	I	TMRB4 Input1	
	PG4	I/O	Input Output Port	
55	TB4IN0	I	TMRB4 Input0	
FG	PG5	I/O	Input Output Port	
56	TB2IN1	1	TMRB2 Input1	
57	PH0	I/O	Input Output Port	
57	TB4OUT	0	TMRB4 Output	
58	PH1	I/O	Input Output Port	
56	TB2OUT	0	TMRB2 Output	
59	PH2	I/O	Input Output Port	
60	PH3	I/O	Input Output Port	
00	TB5IN1	I	TMRB5 Input1	
61	PH4	I/O	Input Output Port	
01	TB5IN0	I	TMRB5 Input0	
62	PH5	I/O	Input Output Port	
UZ	TB3IN1	I	TMRB3 Input1	
63	DVSS	-	GND pin	(Note 2)
64	DVDD3	-	Power supply pin for Digital circuit	

Note 5: Connect with low frequency X'tal resonator. If low frequency X'tal resonator is not connected, XT1 must be pull-up with resistor $(10k\Omega)$ and XT2 must be open.

Note 6: Must be connected GND.

Note 7: Connect with High frequency X'tal resonator for high accuracy clock.

Table 6.4 Pin Function

Pin Number	Pin symbol	I/O	Description	Comment
05	PI0	I/O	Input Output Port	
65	SCOUT	0	Clock output	
66	PI1	I/O	Input Output Port	
67	PI2	I/O	Input Output Port	
68	PI3	I/O	Input Output Port	
69	PI4	I/O	Input Output Port	
70	PI5	I/O	Input Output Port	
71	TEST	I	TEST pin (pull-up)	(Note 8)
72	NGD1	0	VCC1-4.5V LDO output pin for internal circuit 1	(Note 9)
73	PVDD	-	System power supply pin	
74	VDD33	I/O	3.3V LDO Output or Input pin	
75	PGND1	-	GND pin	(Note 2)
76	VCC1	-	Power supply pin for CH1 to CH4 Pre-drivers 1	(Note 10)
77	VIN1	I	Capture input: Voltage1	
78	VIN2	I	Capture input: Voltage2	
79	VIN3	I	Capture input: Voltage3	
80	VIN4	I	Capture input: Voltage4	
81	IIN1	I	Capture input: Current1	
82	IIN2	ı	Capture input: Current2	
83	IIN3	I	Capture input: Current3	
84	IIN4	ı	Capture input: Current4	
85	HDRV1	0	High Gate driving force 1	
86	LDRV1	0	Low Gate driving force 1	
87	HDRV2	0	High Gate driving force 2	
88	LDRV2	0	Low Gate driving force 2	
89	HDRV3	0	High Gate driving force 3	
90	LDRV3	0	Low Gate driving force 3	
91	HDRV4	0	High Gate driving force 4	
92	LDRV4	0	Low Gate driving force 4	
93	HDRV5	0	High Gate driving force 5	
94	LDRV5	0	Low Gate driving force 5	
95	HDRV6	0	High Gate driving force 6	
96	LDRV6	0	Low Gate driving force 6	
97	HDRV7	0	High Gate driving force 7	
98	LDRV7	0	Low Gate driving force 7	
99	HDRV8	0	High Gate driving force 8	
100	LDRV8	0	Low Gate driving force 8	

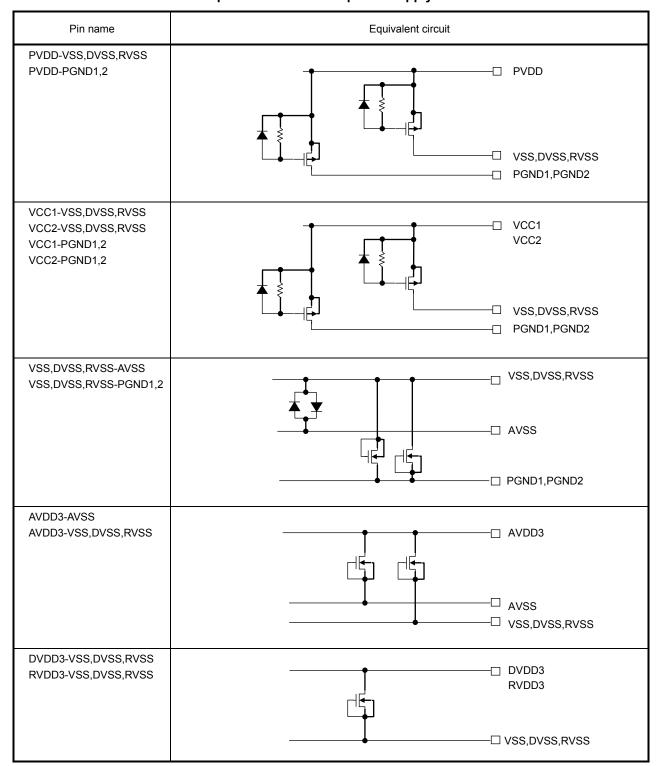
Note 8: Control input/output VDD33. When using external power supply for VDD33, set TEST="L" level.

Note 9: It is impossible to supply power to external parts. Connect capacitor (0.01 μF) between NGD1 and VCC1.

Note 10: When it's not in use, connect to GND.

7. Equivalent circuits for input/output/power supply terminals

Table 7.1 Equivalent circuits for power supply terminals



Pin name Equivalent circuit PA0 PA2-PA6 PF0 Output Data PF1 Open drain Control Output Control -Input Control Pull up Control $50k\Omega$ (typ.) PA1 Output Data Open drain Control Output Control -Input Control 50kΩ (typ.) Pull down Control

Table 7.2 Equivalent circuits of Input / Output terminals

Pin name Equivalent circuit PI0-PI5 Output Data Output Control -Input Control 50kΩ (typ.) Pull down Control · PC0-PC6 Output Data Open drain Control Output Control -Input Data Input Control PD0-PD6 AIN PE0-PE6 Output Data Output Control Input Control

Table 7.3 Equivalent circuits of Input / Output terminals

Pin name Equivalent circuit PG0-PG5 PH0-PH5 Output Data **Dutput Control** Input Data Input Control X1 X2 Clock Oscillator Circuit 500kΩ 1kΩ (typ.) (typ.) High-frequency Oscillation Enable XT1 XT2 Oscillator Circuit XT2 300kΩ (typ.) Low-frequency Oscillation Enable ___ XT1 **XRESET** Pull-up Resistor Input Port Schmitt

Table 7.4 Equivalent circuits of Input / Output terminals

Pin name Equivalent circuit MODE Input Port MODE ← Schmitt (Note)MODE pin is fixed to GND. FTEST3 FTEST3 ◀ Open (Note)FTEST3 pin is fixed to Open. TEST –□ PVDD $1 M\Omega(\text{typ.})$ -□ TEST Internal circuit -□ VSS,DVSS,RVSS IIN1-IIN4 -□ VDD33 VIN1-VIN4 IIN1-IIN4 Internal circuit VIN-VIN4

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Table 7.5 Equivalent circuits of Input terminals

Note: Equivalent circuits may be simplified to illustrate circuits.

-□ VSS,DVSS,RVSS

Pin name Equivalent circuit VDD33 -□ PVDD -□ VDD33 USS,DVSS,RVSS -□ PGND1,PGND2 NGD1 - PVDD NGD1 NGD2 -□ VSS,DVSS,RVSS LDRV1-4 -□ VCC1 HDRV1-4 LDRV1-4 HDRV1-4 -□ PGND1,PGND2 LDRV5-8 -□ VCC2 HDRV5-8 LDRV5-8 HDRV5-8 -□ PGND1,PGND2

Table 7.6 Equivalent circuits of Output terminals

8. Function

8.1 General outline of wireless power system

Qi compliant wireless power system consists of the first side (TX) which transmits power and the second side (RX) which receives power. Power is transmitted by adjoining coils included in TX and RX and by sharing and combining flux. RX controls the power by monitoring receiving power and sending feedback signal to TX. TX controls the power by controlling transmitting power with feedback signal which is received from RX. Configuration example of wireless power system is shown in Figure 8.1.

Communication signal from RX to TX is transmitted (modulated) by ASK modulation. The communication rate and its packet in this communication are defined by Qi compliant. Communication rate is 2kbps. Packets are ID, identification signal, error information, receive power, and stop signal. TX stops its operation in normal mode. It is powered on intermittently and confirms the existence of RX on the TX pad. When TX recognizes RX and succeeds the identification, transmit operation starts. TX continues transmit operation until TX cannot recognize the existence of RX or receives transmit stop signal from RX.

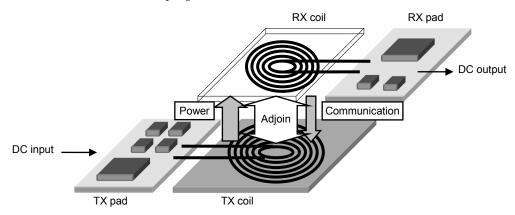


Figure 8.1 General outline of Wireless power system

8.2 Processor Core

The TB6865AFG has a high-performance 32-bit processor core (the ARM Cortex-M3 processor core). For information on the operations of this processor core, please refer to the "Cortex-M3 Technical Reference Manual" issued by ARM Limited. This chapter describes the functions unique to the TB6865AFG that are not explained in that document.

8.2.1 Information on the processor core

The following table shows the revision of the processor core in the TB6865AFG.

Constant AHB control

Refer to the detailed information about the CPU core and architecture; refer to the ARM manual "Cortex-M series processors" in the following URL: http://infocenter.arm.com/help/index.jsp

Product Name	Core Revision
TB6865AFG	r2p1

8.2.2 Configurable Options

The Cortex-M3 core has optional blocks. The following table shows the configurable options in the TB6865AFG.

Configurable Options Implementation Two Internal comparators **FPB** Six Instruction comparators DWT Four comparators ITM Implementable MPU Not implementable ETM Implementable AHB-AP Implementable AHB Trace Macro cell Interface Implementable **TPIU** Implementable WIC Not implementable Debug Port JTAG / Serial Wire Bit Band Present

Absent

Table 8.1 Option

8.3 Reset

The TB6865AFG has four reset sources: an external reset pin (XRESET), a low voltage detection reset (LVD) and the setting <SYSRESETREQ> in the Application Interrupt and Reset Control Register. For reset from the LVD, refer to the 8.10 LVD.

For reset from <SYSRESETREQ>, refer to "Cortex-M3 Technical Reference Manual".

8.4 High Resolution PWM Output: (HRPWM)

HRPWM unit consists of four PWM outputs and TB6865AFG has two units of this HRPWM. The functions are as follows.

• Outputs : Eight channels (four channels x two unit)

- Unit1: PWMOUT1/2, PWMOUT3/4, Unit2: PWMOUT5/6, PWMOUT7/8

- It can connect Full Bridge Inverter

• PWM Frequency : 90kHz to 205kHz and 250kHz

• Frequency step : Under 100Hz

• Dead time generator : 50ns to 10µs, 50ns step

8.5 Capture Communication port

Capture Communication Port is use for communication from RX to TX that is defined by Wireless Power Consortium(WPC). (Note)

This IC has four channels of Capture Communication Port. And they can be used independently.

Their features are given in the following.

- Automatic decoding with backscatter modulation signal
- It can be busy to up to ten words

Note: Please refer to WPC document that is "System Description, Wireless Power Transfer, Volume I: Low Power, Part 1: Interface Definition, Version 1.0.3, September 2011".

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8.6 Pre driver

TB6865AFG has 16 pre-drivers for full-bridge invertor.

8.6.1 Configuration

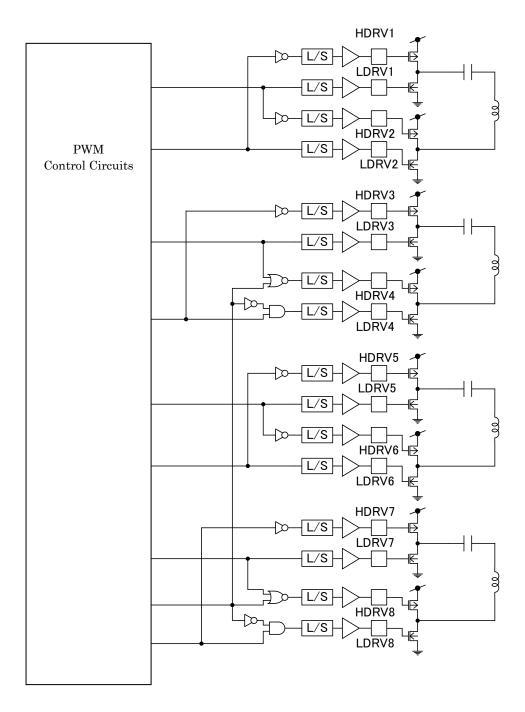


Figure 8.2 Pre-driver circuit

8.7 LDO

TB6865AFG has three LDOs. VDD33 is for MCU block and NGD1, NGD2 are for Pre driver. User cannot use these LDOs output since they are only used for inside circuit of this product.

8.7.1 VDD33 (Output pin mode)

VDD33 is 3.3V voltage source for MCU block. Connect capacitor of $1\mu F$ to GND.

8.7.2 NGD1,NGD2

NGD1 and NGD2 are LDOs which are used in pre-driver block. Note: Connect capacitor of $0.01\mu F$ to VCC.

8.8 Analog/Digital Converter (ADC)

TB6865AFG contains a 12-bit, sequential-conversion analog/digital converter (ADC) with 14 analog input channels.

These 14 analog input channels (pins AIN00 through AIN13) are also used as input/output ports.

8.9 Power on reset (POR)

The power-on-reset circuit (POR) generates a power-on reset signal when power-on. Power supply voltage is indicated as DVDD3(=AVDD3=RVDD3).

8.9.1 Configuration

Power-on-reset circuit consists of the reference voltage generation circuit, comparators, the LVD reset circuit and the power-on counter.

This circuit compares a voltage divided by the ladder resistor with a reference voltage generated in the reference voltage generation circuit in the comparator.

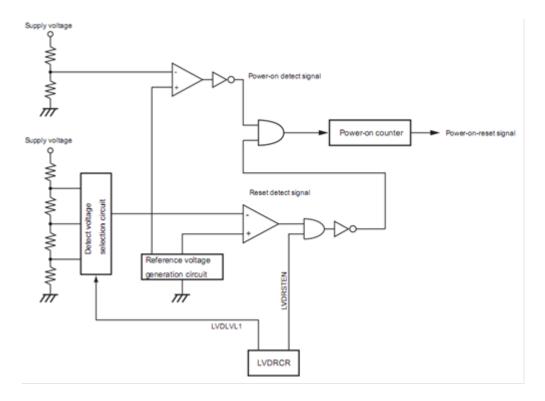


Figure 8.3 Power-on-reset circuit

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For details of LVDRCR in LVD reset circuit, refer to Section "Low Voltage Detection Circuit (LVD)".

8.10 Low Voltage Detection Circuit (LVD)

Voltage detection circuit generates a reset signal or an interrupt signal (NMI) by detecting a decreasing/increasing voltage.

Supply voltage is indicated as DVDD3(=AVDD3=RVDD3).

Note: Due to the fluctuation of supply voltage, the power-on reset circuit may not operate properly. Users should give due consideration based on the electrical characteristic in the device designing.

8.10.1 Configuration

The voltage detection circuit consists of a reference voltage generation circuit, comparators and control registers.

Supply voltage is divided by a ladder resistor and input to the voltage selection circuit. In the voltage selection circuit, a voltage is chosen according to the detected voltage then compared with the reference voltage in the comparator. If the supply voltage is upper/lower than the detected voltage, a reset/interrupt signal occurs.

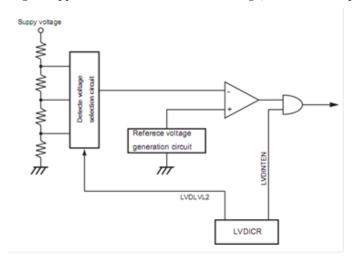


Figure 8.4 Block diagram of LVD (LVD interrupt circuit)

8.10.2 Power On and Power Off sequence

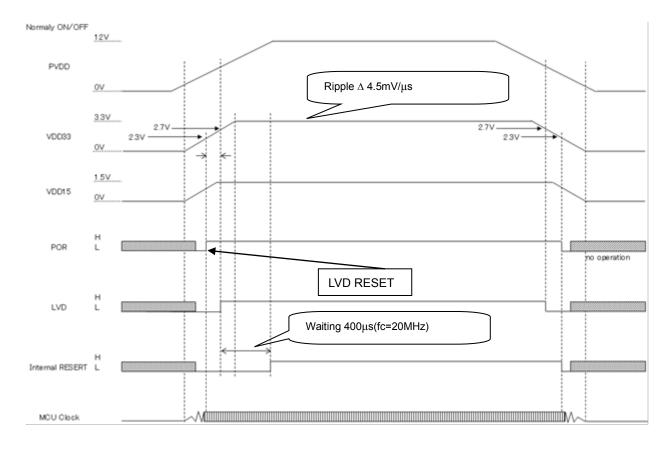


Figure 8.5 Power on Power off sequence

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Note: POR, LVD, Internal RESET are "low" active.

9. Absolute Maximum Ratings (Ta= 25°C)

Table 9.1 Absolute Maximum Ratings

Chara	acteristics	Symbol	Rating	Unit	
		DVDD3			
		AVDD3	-0.3 to 3.9	V	
		RVDD3			
Supply Voltage		PVDD			
		VCC1	-0.3 to 24	V	
		VCC2			
Input Voltage 0 (N	Note 1)	VIN	-0.3 to 3.9	V	
Input Voltage 2 (N	Note 2)	V _{IN2}	-0.3 to min(5.5, PVDD+0.3)	V	
Input Voltage 3 (N	Note 3)	V _{IN3}	-0.3 to VIN2+0.3	V	
Low-level	Per pin	loL	5		
Output Current	Total	ΣI _{OL}	50		
Low-level Large	Per pin	loL	16	4	
Output Current	Total	ΣI _{OL}	50	mA mA	
High-level	Per pin	Гон	-5		
Output Current	Total	ΣΙΟΗ	-50		
Output Voltage 1	(Note 4)	Vout1	-0.3 to VCC1+0.3	V	
Output Voltage 2	(Note 5)	V _{OUT2}	-0.3 to VCC2+0.3	V	
Output Current	(Note 6)	IOUT1	500	mA	
Power Consumpt (Except during Fl	ion ash W/E, Ta=25°C)	PD1	2780	mW	
	Power Consumption (During Flash W/E, Ta=25°C)		1670	mW	
Soldering Temperature (10s)		T _{SOLDER}	260	°C	
Storage Tempera	iture	T _{STG}	-40 to 125	°C	
Operating Temperature	Expect during Flash W/E	T _{OPR}	-40 to 85	°C	
remperature	During Flash W/E		0 to 70		

Note: The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

Exceeding the rating (s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

Please use the IC within the specified operating ranges.

Note 1: Apply to input terminals except Note 2, 3.

Note 2: Apply to VDD33 terminal (when TEST=0). A = min(A, B) when $A \le B$. B = min(A, B) when A > B.

Note 3: Apply to VIN[4:1] and IIN[4:1] terminals.

Note 4: Apply to HDRV[4:1] and LDRV[4:1] terminals.

Note 5: Apply to HDRV[8:5] and LDRV[8:5] terminals.

Note 6: Apply to HDRV[8:1] and LDRV[8:1] terminals.

10. DC Electrical Characteristics

10.1 DC Electrical Characteristics(MPU part)(1/3)

Table 10.1 DC Electrical Characteristics (MPU part)(1/3)

(Unless otherwise specified, DVSS=AVSS=RVSS=0V, Ta= -40 to 85°C)

Character	istics	Symbol	Test condition	Min	Typ. (Note 1)	Max	Unit
Supply voltage	DVDD3 AVDD3 RVDD3 (Note 2)	DVDD3 AVDD3 RVDD3	fosc = 20MHz fsys = 1 to 20MHz	2.7	-	3.6	٧
Low-level input v	oltage	VIL1	2.7V ≦DVDD3 ≦3.6V	-0.3	-	0.25× DVDD3	V
High-level input	voltage	V _{IH1}	2.7V ≦DVDD3 ≦3.6V	0.75 × DVDD3	-	DVDD3+0.3	V
		V _{OL1}	IOL=2mA 2.7V ≦DVDD3 ≦3.6V <except pc1="" pc6="" to=""></except>	-	-	0.4	V
Low-level output	Low-level output voltage		IOL=10mA 2.7V ≦DVDD3 ≦3.6V <pc1 pc6="" to=""></pc1>	-	-	0.4	V
High-level output	High-level output voltage		IOH=-2mA 2.7V ≦DVDD3 ≦3.6V	2.4	-	-	V
Input leakage cu	rrent	ILI	0.0V ≦VIN ≦DVDD3 0.0V ≦VIN ≦AVDD3	-	0.02	± 5	
Output leakage of	current	ILO	0.2V ≦VIN≤ (DVDD3-0.2) 0.2V ≦VIN≤ (AVDD3-0.2)	-	0.05	± 10	μА
Pull-up resistance (RESET pin)		R _{RST}	DVDD3 =2.7V to 3.6V	-	50	150	kΩ
Schmitt triggered port		VTH1	2.7V ≦DVDD3 ≦3.6V	0.3	0.6	-	V
Programmable pull-up/pull-dowr	n resistance	P _{KH}	DVDD3=2.7V to 3.6V	-	50	150	kΩ
Pin capacitance (except power su	upply pins)	Cio	fc =1MHz	-	-	10	pF

Note 1: Unless otherwise specified, Ta=25°C, DVDD3=RVDD3=AVDD3=3.3 V

Note 2: The same voltage must be supplied to DVDD3, AVDD3 and RVDD3.

Note 3: Ensure that all power supply source is power-off and then power-on again when DVDD3, RVDD3 and AVDD3 falls below 2.7V which is minimum operating voltage

10.2 DC Electrical Characteristics(MPU part) (2/3)

Table 10.2 DC Electrical Characteristics(MPU part) (2/3)

Characteristics	Symbol	Test condition	Min	Typ. (Note 1)	Max	Unit	
Low-level output current	I _{OL1}	2.7V ≦DVDD3 ≦3.6V < Except PC1 to PC6> per pin	-	-	2	mA	
	lOL2	2.7V ≦DVDD3 ≦3.6V <pc1 pc6="" to=""> per pin</pc1>	-	-	10	mA	
	ΣI _{OL}	Total	-	-	35	111/4	
High-level output current	Іон	2.7V ≦DVDD3 ≦3.6V Per pin	-	-	-2.0	mA	
Current	ΣΙΟΗ	Total	-	-	-35		

Note 1: Unless otherwise specified, Ta=25°C, DVDD3=RVDD3=AVDD3=3.3 V

10.3 DC Electrical Characteristics(MPU part) (3/3)

Table 10.3 DC Electrical Characteristics(MPU part) (3/3)

Characteristics	Symbol	Test condition	Min	Typ. (Note 1)	Max	Unit
NORMAL(Note 2) Gear1/1		fsys = 20 MHz	-	15	20	mA
IDLE (Note 3)	IDD		-	7	12	
STOP1		fs = 32.768kHz	-	150	650	μА

Note 1: Unless otherwise specified, Ta=25°C, DVDD3=RVDD3=AVDD3=3.3 V.

Note 2: IDD NORMAL: Measured with Dhrystone ver.2.1 operated in FLASH. All functions operate excluding A/DC and D/AC.

Note 3: IDD IDLE: Measured with all functions stopped. The currents flow through DVDD3, AVDD3 and RVDD3 are included.

10.4 DC Electrical Characteristics(Analog part)

Table 10.4 LDO33

(Unless otherwise specified, COUT=1.0 μ F, PVDD=12V, Ta = 25°C)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Supply voltage	PVDD		4.5	-	14	V
Output voltage	VDD33		2.7	-	3.6	V
Output current	lout33		-	60	-	mA
Line regulation	Line33	PVDD=5V→14V lout33=1mA	-	-	33	mV
Load regulation	Load33	PVDD=5V lout33=0mA→60mA	-	-	165	mV

Table 10.5 NGD1, NGD2

(Unless otherwise specified, COUT=0.1µF, PVDD=12V, Ta=25°C)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Supply voltage	VCC1 VCC2		4.5	-	14	V
Output voltage	NGD1		-	VCC1-4.5	-	V
Output voltage	NGD2		-	VCC2-4.5	-	V
Outside suggests	loutNGD1	NGD1=VCC1-4.5V	-	15	-	mA
Output current	loutNGD2	NGD2=VCC2-4.5V	-	15	-	IIIA

Table 10.6 Pre driver

(Unless otherwise specified, PVDD=12V, Ta=25°C)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Supply voltage	VCC1 VCC2		4.5	-	14	٧
High side MOS Ron	RonH	lds=0.1A	-	-	10	Ω
Low side MOS Ron	RonL	Ids=0.1A	-	-	10	Ω
Slew rate rise	Tr	Output capacitor=1000pF	-	-	100	ns
Slew rate fall	Tf	Output capacitor=1000pF	-	-	100	ns

Table 10.7 Filter

(Unless otherwise specified, PVDD=12V, Ta=25°C)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Supply voltage	VDD33		2.7	-	3.6	V
Cutoff frequency (LPF)	FcLPF		2.9	5	7.5	kHz
Differential input range	Rdiff		-	20	VDD33	mV

10.5 12-bit ADC Electric Characteristics

Table 10.8 12-bit ADC Electric Characteristics

DVDD3=AVDD3=RVDD3=VREFH=2.7V to 3.6V, AVSS=DVSS, Ta= -40 to 85°C

AVDD3 load capacitance \geq 3.3 μF , VREF load capacitance \geq 3.3 μF

Characteristics		Symbol	Test condition	Min	Тур.	Max	Unit
Analog reference voltage(+)		AVREFH	-	2.7	3.3	3.6	V
Analog input voltage		VAIN	-	AVSS	-	VREFH	V
Power supply current of analog reference voltage	AD conversion	IREF	DVSS = AVSS	-	2.0	2.5	mA
	Non-AD conversion			-	-	5	μА
Supply current	AD conversion	ADIcc	Except IREF	-	1.0	2.0	mA
INL error				-	-	±9	
DNL error Offset error Full-scale error		- AI	AIN resistance \leq 1 k Ω AIN load capacitance \leq 0.1 μ F Conversion time \geq 2.0 μ s (ADCLK=20MHz)	-	-	±9	LSB
				-	-	±9	
				-	-	±9	
Total error	rror			-	-	±9	
Conversion time		Tconv	ADCLK=20MHz	2	-	10	μS

Note: 1LSB = (AVREFH - AVSS)/4096 [V] Note: Peripheral functions are disabled.

±9LSB@12bit -> ±2.25LSB@10bit

10.6 On chip oscillator

Table 10.9 On chip oscillator

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Oscillating frequency	IHOSC	Ta = 0 to 85°C	1	20	1	MHz

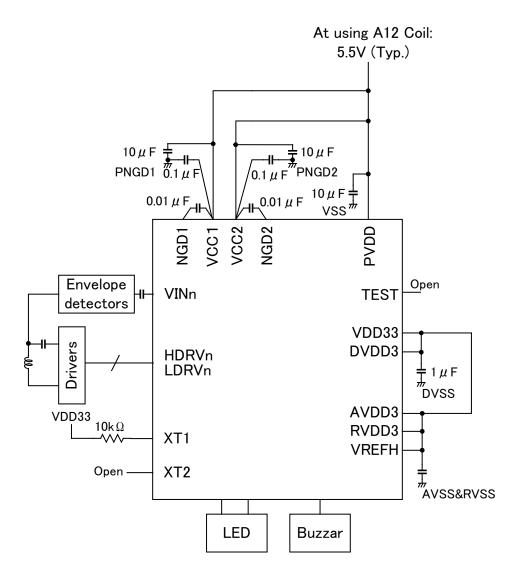
Note: ±3%

10.7 Electrostatic Discharge(ESD)

Note: Caution about the electric discharge(ESD) sensitivity of this product.

For ESD test data of this product, please contact your local Toshiba sales representative.

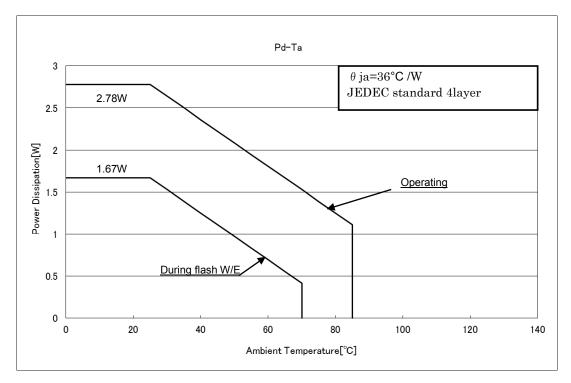
11. Application circuit



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12. Thermal Estimation

This figure is allowable power dissipation graph of TB6865AFG.



You have to design PCB layout so that power loss does not go beyond this Pd-Ta line in this graph.

This graph is based on JEDEC standard 4 layers PCB. Thermal resistance strongly depends on the size of PCB, the pattern layout, and the number of layer of PCB.

You can thermal calculation with following formulas.

• Using built-in 3.3V LDO. $\Delta T = \theta ja \times (Vpvdd \times Ipvdd + Vvcc \times Ivcc + Vpvdd \times Ivdd)$

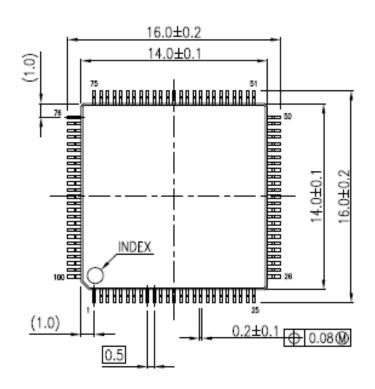
Vpvdd =PVDD voltage
Ipvdd =PVDD current
Vvcc=VCC1 voltage=VCC2 voltage
Ivcc=VCC1 current + VCC2 current
Vvdd=VDD33 voltage=DVDD3 voltage=AVDD3 voltage=RVDD3 voltage
Ivdd33=VDD33 current
Imcu=MCU current
Iled= Indicator LED current
Ivdd=Ivdd33+Imcu+Iled

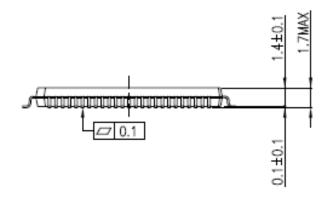
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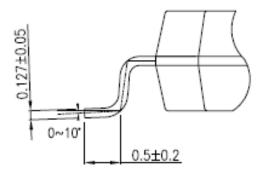
13. Package Dimensions

LQFP100-P-1414-0.50G

Unit: mm







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Weight: 0.62g (typ.)

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